

60V AUTO-GRADE N-CHANNEL MOSFET



Features

- AEC-Q101 qualified
- Low on-resistance of 5.5mΩ
- Operating junction temperature capability up to
- Low gate charge (QG)DFN3333-8(SWF) package with side-wettable flanks



Benefits

Low conduction losses and an impressive RDS(on) of only $5.5 \text{m}\Omega$ reduce power loss and boost efficiency.

Low gate charge facilitates high efficiencies at both low and high loads, making it ideal for demanding automotive applications.

Applications



Battery management systems (BMS)





Superior Automotive Performance & Low RDS(on)



Engineered for Efficiency



Low-Profile Package & Low Gate Charge (QC)





Product Attributes, Parametrics & Datasheets

Product	Туре	Package	Drain- SourceVoltage VDS	Drain- SourceOn- Resistance (max.)RDS(on)	Mounting Type	Datasheet
MCGWF5D5N06YLHE3	N-Channel Power MOSFET	DFN3333- 8(SWF)	60V	5.5mΩ	Surface- Mount (SMD)	<u>Info</u>

Applications:



Power Management

- DC-DC converters
- · Load switching
- Battery management systems (BMS)



Automotive Control Systems

- Seat control systems
- Electric power steering (EPS)
- Climate control systems
- Infotainment systems



Motor Controls

- Motor drives
- Electric vehicle (EV) drive systems
- Robotics and automation



Lighting

- Lighting controls
- LED drivers

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